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	Application No.	Applicant(s)	3
	10/708,381	CHEN ET AL.	
Notice of Allowability	Examiner	Art Unit	
	Alexander Sofocleous	2824	
The MAILING DATE of this communication appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this or other appropriate communica GHTS. This application is subje	application. If not included ition will be mailed in due co	urse. THIS
1. X This communication is responsive to Amendment filed April	il 25, 2006.		
2. X The allowed claim(s) is/are <u>1,2,4-8 and 15-18</u> .			
3. ☐ Acknowledgment is made of a claim for foreign priority un a) ☐ All b) ☐ Some* c) ☐ None of the:			
1. Certified copies of the priority documents have			
2. Certified copies of the priority documents have	•		- f Al
3. Copies of the certified copies of the priority doc	cuments have been received in t	inis national stage application	n from the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		ply complying with the requi	rements
4. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give			TICE OF
5. CORRECTED DRAWINGS (as "replacement sheets") mus	st be submitted.		
(a) I including changes required by the Notice of Draftspers	on's Patent Drawing Review (P	TO-948) attached	
1) 🗌 hereto or 2) 🔲 to Paper No./Mail Date			
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date			
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written on the di he header according to 37 CFR 1.	rawings in the front (not the ba 121(d).	ack) of
6. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT			te the
Attachment(s) 1. ⊠ Notice of References Cited (PTO-892)	5. Notice of Inform	nal Patent Application (PTO-	152)
Notice of References Cited (P10-092) Notice of Draftperson's Patent Drawing Review (PT0-948)	6. Interview Sumn	* *	102)
	_ Paper No./Mai		
 Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 	08), 7. ∐ Examiner's Ame	endment/Comment	
4. Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. ⊠ Examiner's Stat	tement of Reasons for Allowa	ance
	/ Journey		
		RICHARD ELMS /ISORY PATENT EXAMINER HNOLOGY CENTER 2800	

DETAILED ACTION

1. This action is responsive to the following communication: the Amendment filed April 25, 2006.

2. Claims 1-2, 4-8, and 15-18 are pending in the case. Claims 3, 9-14, and 19-20 are cancelled. Claims 1, 4, and 5 are currently amended. Claims 1 and 15 are independent claims.

Specification

The proposed specification corrections (paragraph 0015-0017) received on April25, 2006 are approved by Examiner.

Drawings

4. The proposed drawings corrections (Figure 5) received on April 25, 2006 are approved by Examiner.

Allowable Subject Matter

- 5. Claims 1-2, 4-8, and 15-18 are allowed.
- 6. The following is an examiner's statement of reasons for allowance:

With respect to independent claim 1, there is no teaching or suggestion in the prior art to the second buried strap region and diffusion region formed in the p-well of the control cell being at a lower depth than the first buried strap region and diffusion

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region formed in the p-well of the storage cell.

With respect to independent claim 15, there is no teaching or suggestion in the prior art to providing two deep trenches: one deep trench including a vertical storage cell and a deep trench capacitor and the other deep trench including a vertical control cell for controlling the threshold voltage of the storage cell by applying a voltage to the common conductor connecting the gate of the storage cell and control cell such that the voltage enables pinch-off resulting in the floating condition of the p-well decreases the threshold voltage when the storage cell is in an on-state or resulting in an increased gate over-drive and drive current when the storage cell is in an off-state.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Chidambarrao et al. (U.S. Patent 6,573,561) show a pair of adjacent DRAM cells with buried straps at the same depth.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Alexander Sofocleous whose telephone number is 571-272-0635. The examiner can normally be reached on M-F 7:00am - 4pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

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supervisor, Richard Elms can be reached on 571-272-1869. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

AGS

REPLACEMENT SHEET 10/708,381

FIS920030367US1





